

# MC14001B Series

## B-Suffix Series CMOS Gates

MC14001B, MC14011B, MC14023B,  
 MC14025B, MC14071B, MC14073B,  
 MC14081B, MC14082B



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The B Series logic gates are constructed with P and N channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

### Features

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range.
- Double Diode Protection on All Inputs Except: Triple Diode Protection on MC14011B and MC14081B
- Pin-for-Pin Replacements for Corresponding CD4000 Series B Suffix Devices
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>)

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient) per Pin	±10	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 1)	500	mW
T <sub>A</sub>	Ambient Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>L</sub>	Lead Temperature (8-Second Soldering)	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### 1. Temperature Derating:

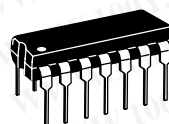
Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>in</sub> and V<sub>out</sub> should be constrained to the range V<sub>SS</sub> ≤ (V<sub>in</sub> or V<sub>out</sub>) ≤ V<sub>DD</sub>.

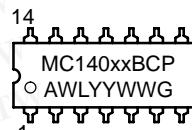
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V<sub>SS</sub> or V<sub>DD</sub>). Unused outputs must be left open.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

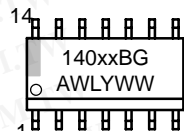
### MARKING DIAGRAMS



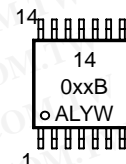
PDIP-14  
 P SUFFIX  
 CASE 646



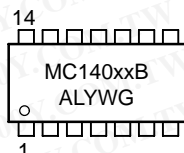
SOIC-14  
 D SUFFIX  
 CASE 751A



TSSOP-14  
 DT SUFFIX  
 CASE 948G



SOEIAJ-14  
 F SUFFIX  
 CASE 965



xx = Specific Device Code  
 A = Assembly Location  
 WL, L = Wafer Lot  
 YY, Y = Year  
 WW, W = Work Week  
 G = Pb-Free Indicator

### DEVICE INFORMATION

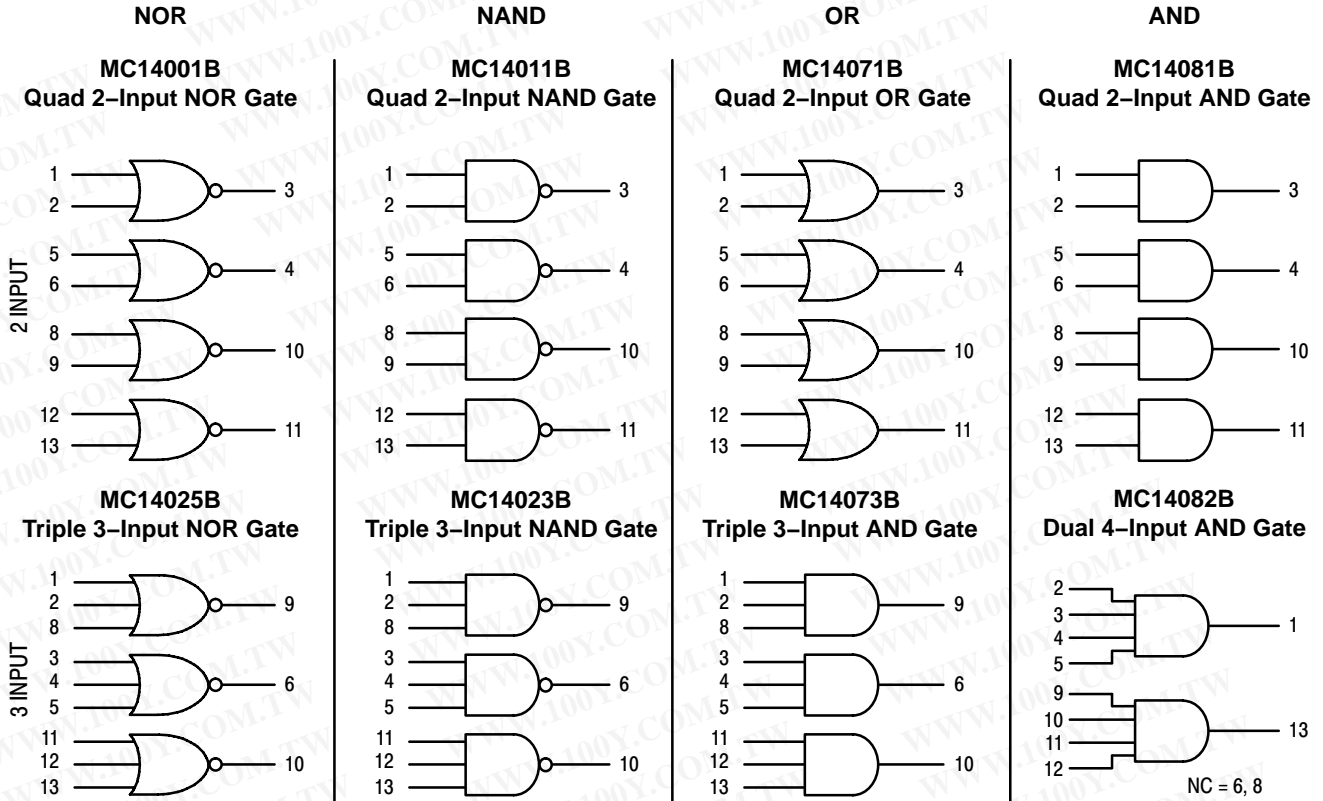
Device	Description
MC14001B	Quad 2-Input NOR Gate
MC14011B	Quad 2-Input NAND Gate
MC14023B	Triple 3-Input NAND Gate
MC14025B	Triple 3-Input NOR Gate
MC14071B	Quad 2-Input OR Gate
MC14073B	Triple 3-Input AND Gate
MC14081B	Quad 2-Input AND Gate
MC14082B	Dual 4-Input AND Gate

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

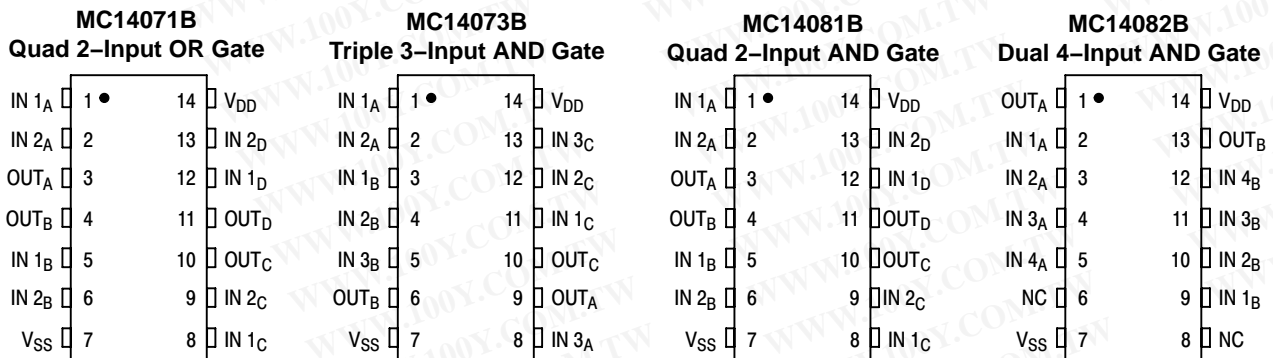
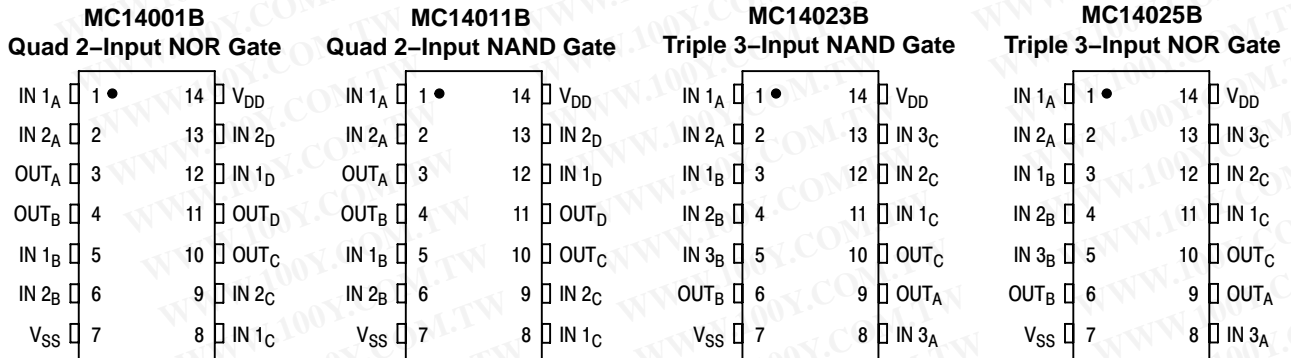
# MC14001B Series

## LOGIC DIAGRAMS



$V_{DD}$  = PIN 14  
 $V_{SS}$  = PIN 7  
 FOR ALL DEVICES

## PIN ASSIGNMENTS



NC = NO CONNECTION

# MC14001B Series

## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	- 55°C		25°C			125°C		Unit
			Min	Max	Min	Typ <sup>(2)</sup>	Max	Min	Max	
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0  V <sub>in</sub> = 0 or V <sub>DD</sub>	"0" Level V <sub>OL</sub>	5.0	-	0.05	-	0	0.05	-	0.05	Vdc
		10	-	0.05	-	0	0.05	-	0.05	
		15	-	0.05	-	0	0.05	-	0.05	
	"1" Level V <sub>OH</sub>	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc
		10	9.95	-	9.95	10	-	9.95	-	
		15	14.95	-	14.95	15	-	14.95	-	
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)  (V <sub>O</sub> = 0.5 or 4.5 Vdc) (V <sub>O</sub> = 1.0 or 9.0 Vdc) (V <sub>O</sub> = 1.5 or 13.5 Vdc)	"0" Level V <sub>IL</sub>	5.0	-	1.5	-	2.25	1.5	-	1.5	Vdc
		10	-	3.0	-	4.50	3.0	-	3.0	
		15	-	4.0	-	6.75	4.0	-	4.0	
	"1" Level V <sub>IH</sub>	5.0	3.5	-	3.5	2.75	-	3.5	-	Vdc
		10	7.0	-	7.0	5.50	-	7.0	-	
		15	11	-	11	8.25	-	11	-	
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)  (V <sub>OL</sub> = 0.4 Vdc) (V <sub>OL</sub> = 0.5 Vdc) (V <sub>OL</sub> = 1.5 Vdc)	Source I <sub>OH</sub>	5.0	-3.0	-	-2.4	-4.2	-	-1.7	-	mAdc
		5.0	-0.64	-	-0.51	-0.88	-	-0.36	-	
		10	-1.6	-	-1.3	-2.25	-	-0.9	-	
		15	-4.2	-	-3.4	-8.8	-	-2.4	-	
	Sink I <sub>OL</sub>	5.0	0.64	-	0.51	0.88	-	0.36	-	mAdc
		10	1.6	-	1.3	2.25	-	0.9	-	
15		4.2	-	3.4	8.8	-	2.4	-		
Input Current	I <sub>in</sub>	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	-	0.25	-	0.0005	0.25	-	7.5	μAdc
		10	-	0.5	-	0.0010	0.5	-	15	
		15	-	1.0	-	0.0015	1.0	-	30	
Total Supply Current <sup>(3) (4)</sup> (Dynamic plus Quiescent, Per Gate, C <sub>L</sub> = 50 pF)	I <sub>T</sub>	5.0 10 15	I <sub>T</sub> = (0.3 μA/kHz) f + I <sub>DD</sub> /N I <sub>T</sub> = (0.6 μA/kHz) f + I <sub>DD</sub> /N I <sub>T</sub> = (0.9 μA/kHz) f + I <sub>DD</sub> /N						μAdc	

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.001 x the number of exercised gates per package.

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# MC14001B Series

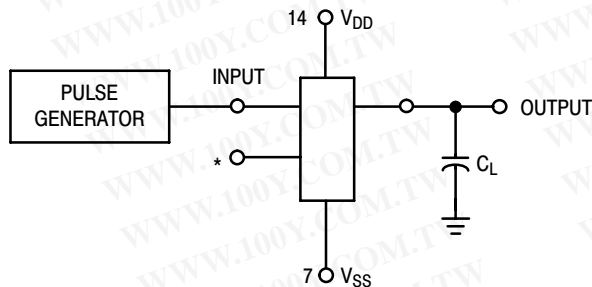
## B-SERIES GATE SWITCHING TIMES

SWITCHING CHARACTERISTICS <sup>(5)</sup> ( $C_L = 50 \text{ pF}$ ,  $T_A = 25^\circ\text{C}$ )

Characteristic	Symbol	V <sub>DD</sub> V <sub>dC</sub>	Min	Typ <sup>(6)</sup>	Max	Unit
Output Rise Time, All B-Series Gates $t_{TLH} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$ $t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$	$t_{TLH}$	5.0 10 15	– – –	100 50 40	200 100 80	ns
Output Fall Time, All B-Series Gates $t_{THL} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$ $t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$	$t_{THL}$	5.0 10 15	– – –	100 50 40	200 100 80	ns
Propagation Delay Time MC14001B, MC14011B only $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 80 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 32 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 27 \text{ ns}$ All Other 2, 3, and 4 Input Gates $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 115 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 47 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 37 \text{ ns}$ 8-Input Gates (MC14068B, MC14078B) $t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 155 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 62 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 47 \text{ ns}$	$t_{PLH}, t_{PHL}$	5.0 10 15  5.0 10 15  5.0 10 15	– – –  – – –  – – –	125 50 40  160 65 50  200 80 60	250 100 80  300 130 100  350 150 110	ns

5. The formulas given are for the typical characteristics only at 25°C.

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



\*All unused inputs of AND, NAND gates must be connected to V<sub>DD</sub>.  
 All unused inputs of OR, NOR gates must be connected to V<sub>SS</sub>.

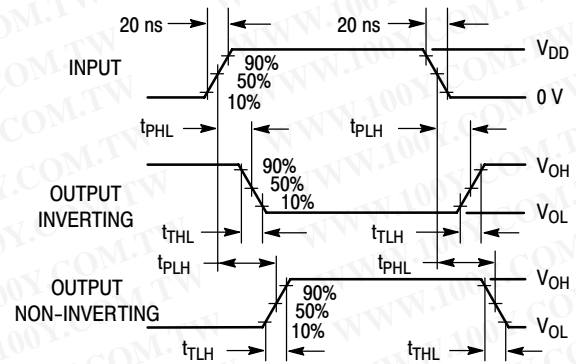


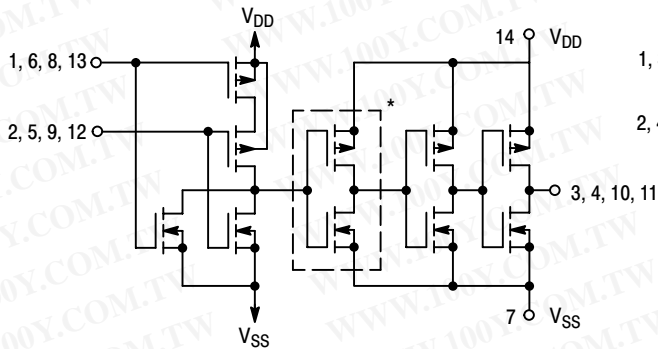
Figure 1. Switching Time Test Circuit and Waveforms

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# MC14001B Series

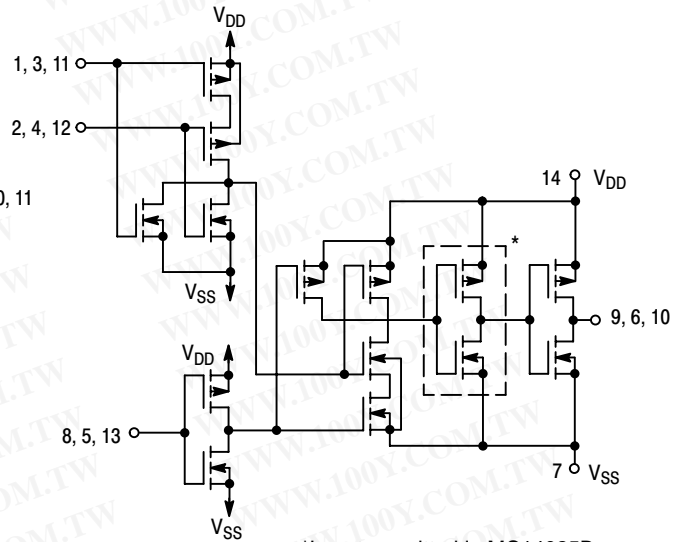
## CIRCUIT SCHEMATIC NOR, OR GATES

**MC14001B, MC14071B**  
One of Four Gates Shown



\*Inverter omitted in MC14001B

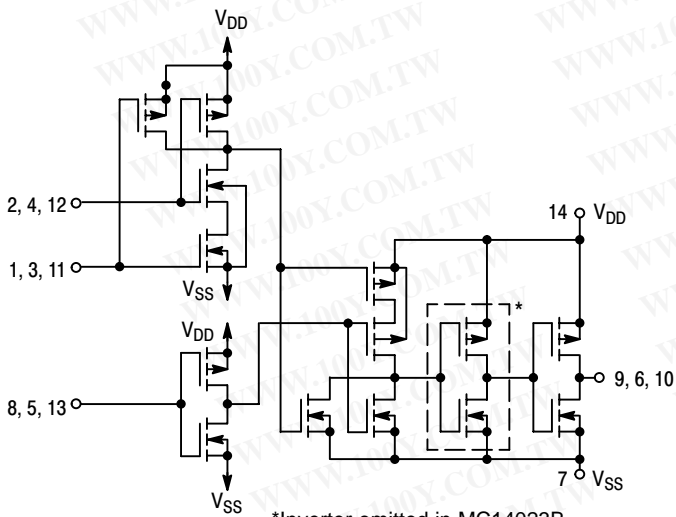
**MC14025B**  
One of Three Gates Shown



\*Inverter omitted in MC14025B

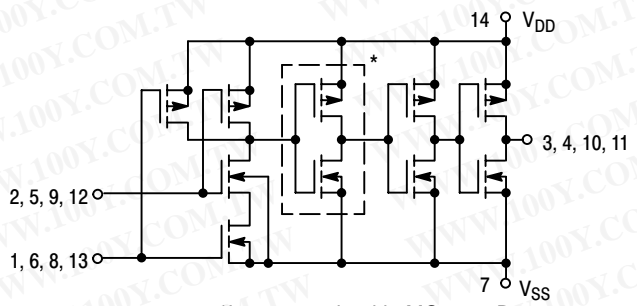
## CIRCUIT SCHEMATIC NAND, AND GATES

**MC14023B, MC14073B**  
One of Three Gates Shown



\*Inverter omitted in MC14023B

**MC14011B, MC14081B**  
One of Four Gates Shown



\*Inverter omitted in MC14011B

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# MC14001B Series

## TYPICAL B-SERIES GATE CHARACTERISTICS

### N-CHANNEL DRAIN CURRENT (SINK)

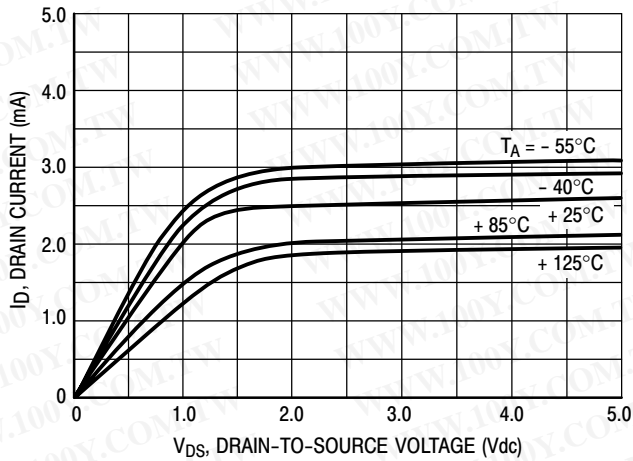


Figure 2.  $V_{GS} = 5.0 \text{ Vdc}$

### P-CHANNEL DRAIN CURRENT (SOURCE)

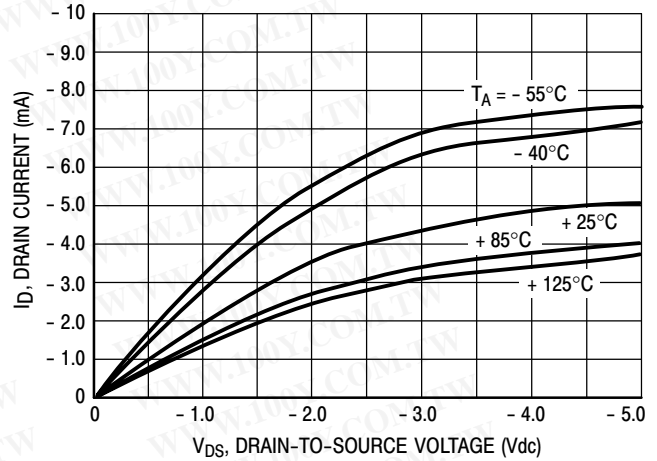


Figure 3.  $V_{GS} = -5.0 \text{ Vdc}$

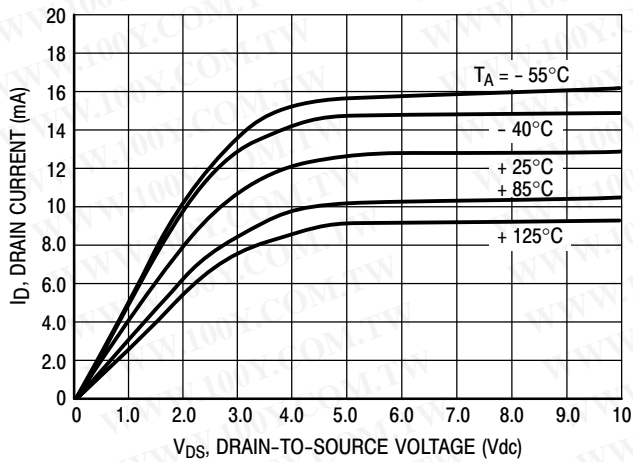


Figure 4.  $V_{GS} = 10 \text{ Vdc}$

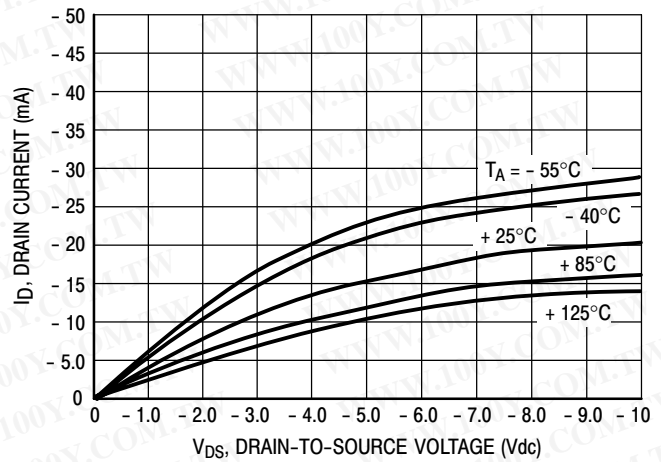


Figure 5.  $V_{GS} = -10 \text{ Vdc}$

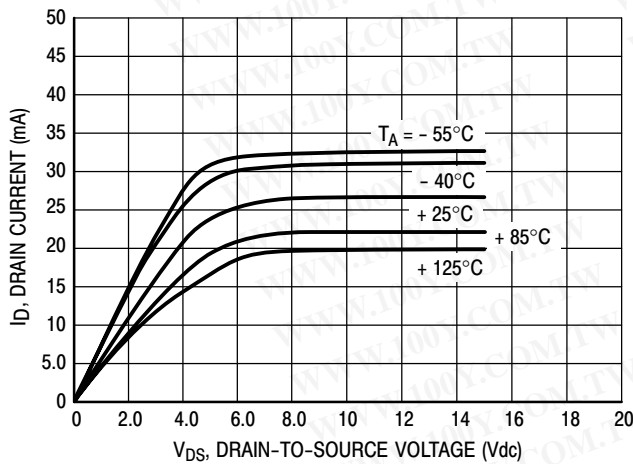


Figure 6.  $V_{GS} = 15 \text{ Vdc}$

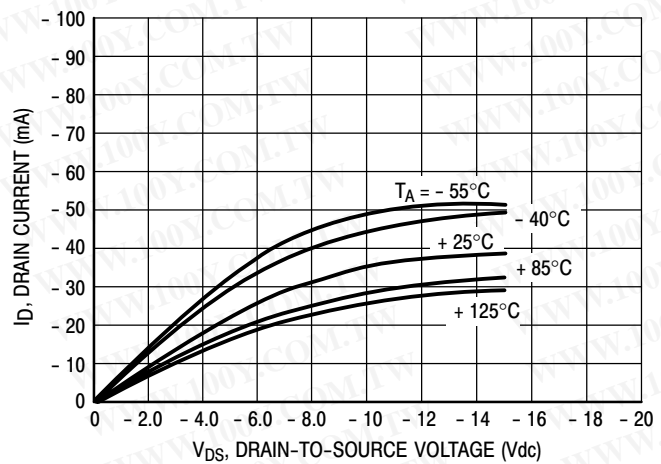


Figure 7.  $V_{GS} = -15 \text{ Vdc}$

These typical curves are not guarantees, but are design aids.  
Caution: The maximum rating for output current is 10 mA per pin.

# MC14001B Series

## TYPICAL B-SERIES GATE CHARACTERISTICS (cont'd)

### VOLTAGE TRANSFER CHARACTERISTICS

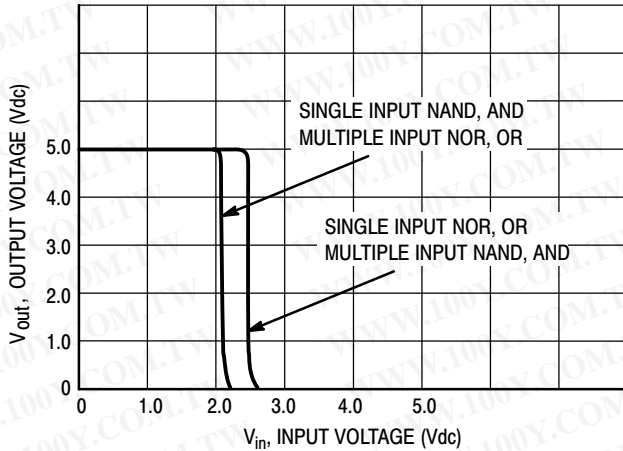


Figure 8.  $V_{DD} = 5.0 \text{ Vdc}$

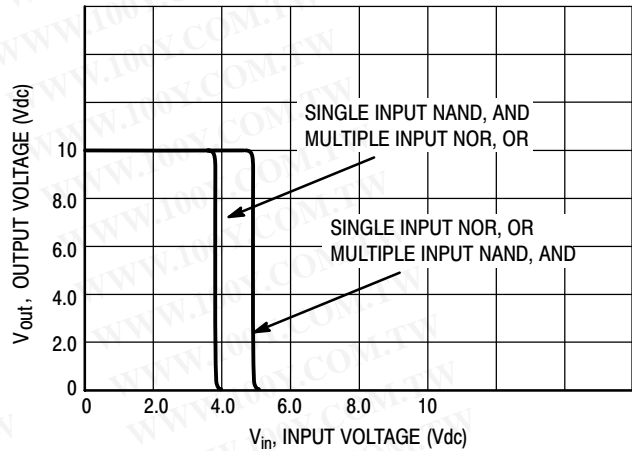


Figure 9.  $V_{DD} = 10 \text{ Vdc}$

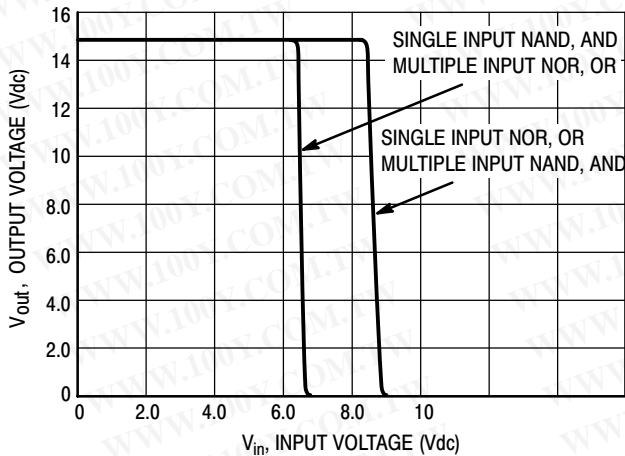


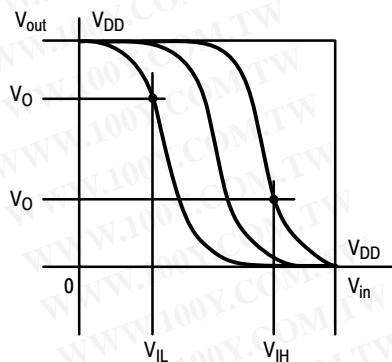
Figure 10.  $V_{DD} = 15 \text{ Vdc}$

### DC NOISE MARGIN

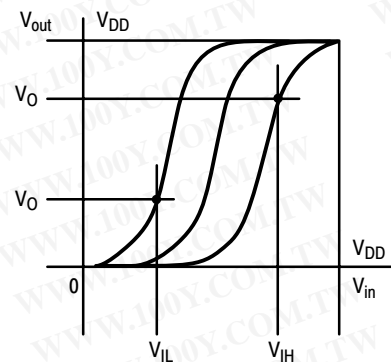
The DC noise margin is defined as the input voltage range from an ideal “1” or “0” input level which does not produce output state change(s). The typical and guaranteed limit values of the input values  $V_{IL}$  and  $V_{IH}$  for the output(s) to be at a fixed voltage  $V_O$  are given in the Electrical Characteristics table.  $V_{IL}$  and  $V_{IH}$  are presented graphically in Figure 11.

Guaranteed minimum noise margins for both the “1” and “0” levels =

- 1.0 V with a 5.0 V supply
- 2.0 V with a 10.0 V supply
- 2.5 V with a 15.0 V supply



(a) Inverting Function



(b) Non-Inverting Function

$V_{SS} = 0 \text{ VOLTS DC}$

Figure 11. DC Noise Immunity

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## MC14001B Series

### ORDERING INFORMATION

Device	Package	Shipping†
MC14001BCP	PDIP-14	2000 Units / Box
MC14001BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14001BD	SOIC-14	2750 Units / Box
MC14001BDR2	SOIC-14	2500 Units / Tape & Reel
MC14001BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14001BDTR2	TSSOP-14*	2500 Units / Tape & Reel
MC14001BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14001BFELG	SOEIAJ-14 (Pb-Free)	2000 Units / Tape & Reel
MC14011BCP	PDIP-14	2000 Units / Box
MC14011BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14011BD	SOIC-14	2750 Units / Box
MC14011BDR2	SOIC-14	2500 Units / Tape & Reel
MC14011BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14011BDTR2	TSSOP-14*	2500 Units / Tape & Reel
MC14011BF	SOEIAJ-14	55 Units / Rail
MC14011BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14011BFELG	SOEIAJ-14 (Pb-Free)	2000 Units / Tape & Reel
MC14023BCP	PDIP-14	2000 Units / Box
MC14023BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14023BD	SOIC-14	2750 Units / Box
MC14023BDR2	SOIC-14	2500 Units / Tape & Reel
MC14023BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14023BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14025BCP	PDIP-14	2000 Units / Box
MC14025BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14025BD	SOIC-14	2750 Units / Box
MC14025BDR2	SOIC-14	2500 Units / Tape & Reel
MC14025BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14025BFEL	SOEIAJ-14	2000 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*This package is inherently Pb-Free.

## MC14001B Series

### ORDERING INFORMATION

Device	Package	Shipping†
MC14071BCP	PDIP-14	2000 Units / Box
MC14071BD	SOIC-14	55 Units / Rail
MC14071BDR2	SOIC-14	2500 Units / Tape & Reel
MC14071BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14071BDT	TSSOP-14*	96 Units per Rail
MC14071BDTR2	TSSOP-14*	2500 Units / Tape & Reel
MC14071BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14073BCP	PDIP-14	2000 Units / Box
MC14073BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14073BD	SOIC-14	55 Units / Rail
MC14073BDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14073BDR2	SOIC-14	2500 Units / Tape & Reel
MC14073BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14073BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14081BCP	PDIP-14	2000 Units / Box
MC14081BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14081BD	SOIC-14	55 Units / Rail
MC14081BDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14081BDR2	SOIC-14	2500 Units / Tape & Reel
MC14081BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel
MC14081BDTR2	TSSOP-14*	2500 Units / Tape & Reel
MC14081BFEL	SOEIAJ-14	2000 Units / Tape & Reel
MC14081BFELG	SOEIAJ-14 (Pb-Free)	2000 Units / Tape & Reel
MC14082BCP	PDIP-14	2000 Units / Box
MC14082BCPG	PDIP-14 (Pb-Free)	2000 Units / Box
MC14082BD	SOIC-14	55 Units / Rail
MC14082BDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14082BDR2	SOIC-14	2500 Units / Tape & Reel
MC14082BDR2G	SOIC-14 (Pb-Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

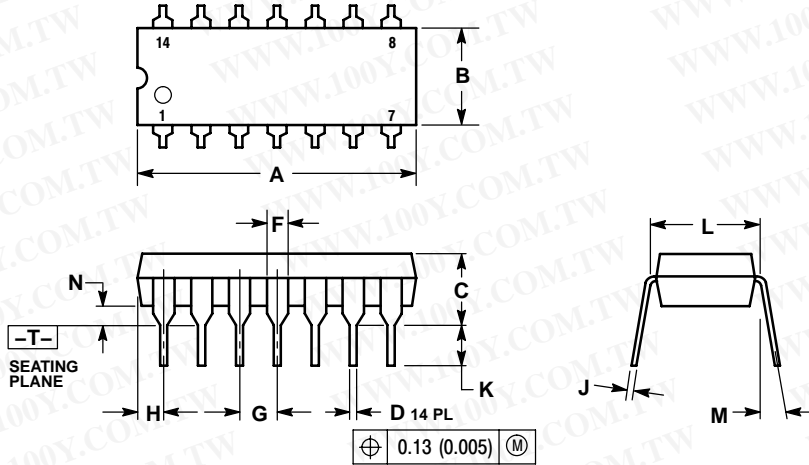
\*This package is inherently Pb-Free.

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## MC14001B Series

### PACKAGE DIMENSIONS

#### P SUFFIX PLASTIC DIP PACKAGE CASE 646-06 ISSUE N

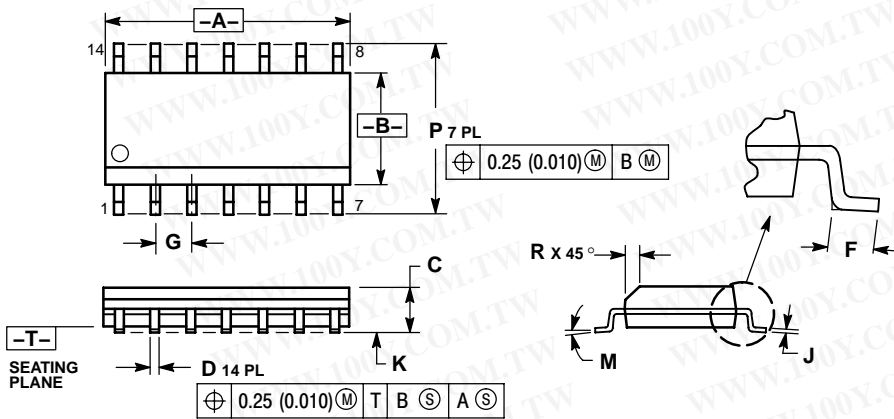


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

#### D SUFFIX PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE G



#### NOTES:

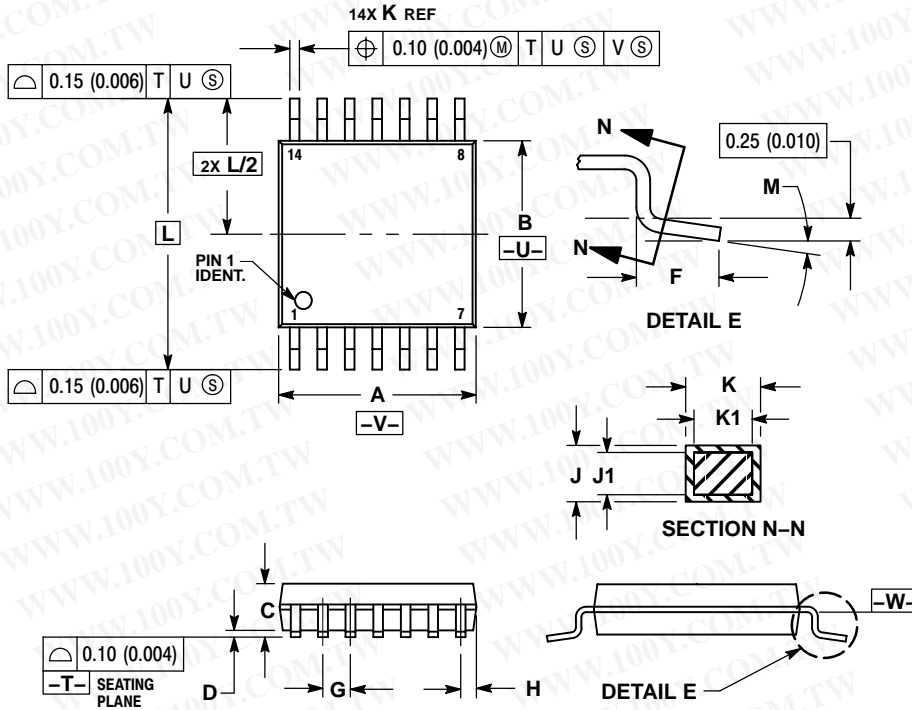
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

# MC14001B Series

## PACKAGE DIMENSIONS

DT SUFFIX  
 PLASTIC TSSOP PACKAGE  
 CASE 948G-01  
 ISSUE 0



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

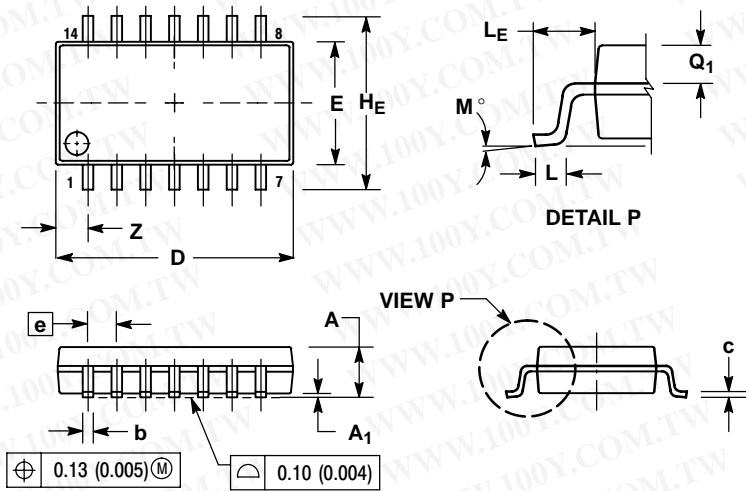
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026	BSC
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40	BSC	0.252	BSC
M	0°	8°	0°	8°

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# MC14001B Series

## PACKAGE DIMENSIONS

### F SUFFIX PLASTIC EIAJ SOIC PACKAGE CASE 965-01 ISSUE O



#### NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 CONTROLLING DIMENSION: MILLIMETER.
- 3 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 5 THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056

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